

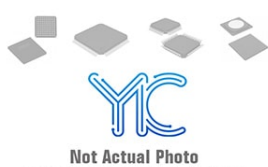
Specifications

Part Number	TPH3R704PL,L1Q
Manufacturer	Toshiba Semiconductor and Storage
Description	MOSFET N-CH 40V 92A TSON
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2511 pcs Stock
Vgs(th) (Max) @ Id	2.4V @ 0.2mA
Vgs (Max)	±20V
Technology	MOSFET (Metal Oxide)
Supplier Device Package	8-SOP Advance (5x5)
Series	U-MOSIX-H
Rds On (Max) @ Id, Vgs	3.7 mOhm @ 46A, 10V
Power Dissipation (Max)	960mW (Ta), 81W (Tc)
Packaging	Tape & Reel (TR)
Package / Case	8-PowerVDFN
Operating Temperature	175°C
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	2500pF @ 20V
Gate Charge (Qg) (Max) @ Vgs	27nC @ 10V
FET Type	N-Channel
FET Feature	-
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	92A (Tc)

In:

**TOSHIBA**  
Leading Innovation >>>

**TPH3R70APL1 ,LHQ(M**  
TOSHIBA  
TOSHIBA QFN8




Not Actual Photo  
YIC International Co., Limited.

**TPH4R003NL**  
TOSHIBA  
TPH4R003NL TOSHIBA

**TOSHIBA**  
Leading Innovation >>>


**TPH3R70APL ,L1Q**  
TOSHIBA  
TOSHIBA QFN


  
 Not Actual Photo  
 YIC International Co., Limited.

**TPH3R704PC**  
 TOSHIBA  
 TPH3R704PC TOSHIBA


**TOSHIBA**  
Leading Innovation >>>

**TPH3R70APL**  
TOSHIBA  
TOSHIBA QFN8



Not Actual Photo  
YIC International Co., Limited.

**TPH3R506PL**  
TOSHIBA  
TPH3R506PL TOSHIBA



**TPH3R203NL,L1Q**  
Toshiba Semiconductor and Storage  
MOSFET N-CH 30V 47A 8-SOP

**TOSHIBA**  
Leading Innovation >>>

**TPH3R506PLLQ(S)**  
TOSHIBA  
TOSHIBA SOP-8

More

Contact us: **Info@YIC-Electronics.com**  
ADD: Unit A5-B5 No.509, 5/F Sing Win Factory Building, 15-17 Shing yip St, Kwun Tong, Kowloon, HongKong.  
Copyright © 2023 YIC-Electronics.com - YIC International Co., Limited